UTC UNISONIC TECHNOLOGIES CO., LTD

DTA123J

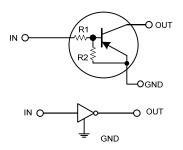
PNP SILICON TRANSISTOR

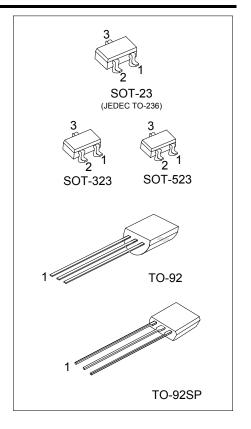
DIGITAL TRANSISTORS (BUILT- IN BIAS RESISTORS)

FEATURES

- * Built-in bias resistors that implies easy ON/OFF applications.
- * The bias resistors are thin-film resistors with complete isolation to allow positive input.

EQUIVALENT CIRCUIT

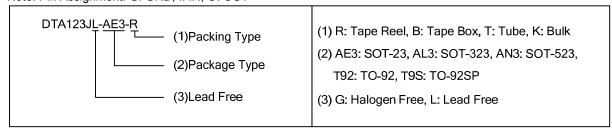




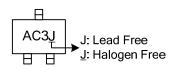
ORDERING INFORMATION

Ordering Number		Deekees	Pin Assignment			Doolsing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
DTA123JL-AE3-R	DTA123JG-AE3-R	SOT-23	G	ı	0	Tape Reel	
DTA123JL-AL3-R	DTA123JG-AL3-R	SOT-323	G	ı	0	Tape Reel	
DTA123JL-AN3-R	DTA123JG-AN3-R	SOT-523	G	ı	0	Tape Reel	
DTA123JL-T92-B	DTA123JG-T92-B	TO-92	G	0	I	Tape Box	
DTA123JL-T92-K	DTA123JG-T92-K	TO-92	G	0	I	Bulk	
DTA123JL-T92-R	DTA123JG-T92-R	TO-92	G	0	Ī	Tape Reel	
DTA123JL-T9S-K	DTA123JG-T9S-K	TO-92SP	G	0	I	Bulk	

Note: Pin Assignment: G: GND, I: IN, O: OUT



MARKING (FOR SOT-23/SOT-323/SOR-523 PACKAGE)



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■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL RATINGS		UNIT
Supply Voltage		V _{CC}	50	V
Input Voltage		V _{IN}	-12 ~ +5	V
Outside Outside		lo	-100	А
Output Current		I _{C(MAX)}	50 V -12 ~ +5 V -100 mA -100 200 150 625 550 150 °C	mA
Power Dissipation	SOT-23/ SOT-323		200	
	SOT-523	D	150	, no \ \ \
	TO-92	P _D	625	mvv
	TO-92SP		550	
Junction Temperature		TJ	150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A =25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
land to Valtage	V _{I (OFF)}	V _{CC} =-5V, I _O =-100μA			-0.5	V
Input Voltage	V _{I (ON)}	V _O =-0.3V, I _O =-5mA	-1.1			V
Output Voltage	$V_{O(ON)}$	$I_0/I_1 = -5 \text{mA}/-0.25 \text{mA}$		-0.1	-0.3	V
Input Current	l _l	V _I =-5V			-3.6	mA
Output Current	I _{O(OFF)}	V_{CC} =-50V, V_1 =0V			-0.5	μΑ
DC Current Gain	Gı	V _O =-5V, I _O =-10mA	80			
Input Resistance	R ₁		1.54	2.2	2.86	ΚΩ
Resistance Ratio	R ₂ /R ₁		17	21	26	
Transition Frequency	f _T	V _{CE} =-10V, I _E =-5mA, f=100MHz (Note)		250		MHz

Note: Transition frequency of the device

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